

## DESCRIPTION

The LM386 is a power amplifier, designed for use in low voltage consumer applications. The gain is internally set to 20 to keep external part count low, but the addition of an external resistor and capacitor between pin 1 and pin 8 will increase the gain to any value up from 20 to 200.

The inputs are ground referenced while the output automatically biases to one-half the supply voltage. The quiescent power drain is only 24 milliwatts when operating from a 6 voltage supply, making the LM386 ideal for battery operation.

## **FEATURES**

- Battery Operation
- Minimum External Parts
- ◆ Wide Supply Voltage Range: 4V~12V
- Low Quiescent Current Drain:4mA
- Voltage Gains:20~200
- Ground Referenced Input
- Self-Centering Output Quiescent Voltage
- Low Distortion:0.2%(Av =20,Vs=6V,RL=8Ω,Po=125mW,f=1kHz)

## **ORDERING INFORMATION**

	Ordering Number	Packago	Packing		
Normal	Lead Free	Halogen Free	Гаскауе	i acking	
LM386-S08-R	LM386L-S08-R	LM386G-S08-R	SOP-8	Tape Reel	
LM386-S08-T	LM386L-S08-T	LM386G-S08-T	SOP-8	Tube	
LM386-P08-R	LM386L-P08-R	LM386G-P08-R	TSSOP-8	Tape Reel	
LM386-P08-T	LM386L-P08-T	LM386G-P08-T	TSSOP-8	Tube	
LM386-D08-T	L <mark>M386</mark> L-D08-T	LM386G-D08-T	DIP-8	Tube	

LM386G- <u>D08-T</u> (1)Packing Type (2)Package Type (3)Halogen Free	(1) R: Tape Reel, T: Tube (2) S08: SOP-8, P08: TSSOP-8, D08: DIP-8 (3) G: Halogen Free, L: Lead Free, Blank: Pb/Sn
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LM386(A



# **PIN CONFIGURATION**



# **ABSOLUTE MAXIMUM RATINGS**

PARAMETER		SYMBOL	RATINGS	UNIT	
Supply Voltage		VCC	15	V	
Input Voltage		VIN	-0.4V ~ +0.4V	V	
	DIP-8		1250		
Power Dissipation	SOP-8	PD	600	mW	
	TSSOP-8		600		
Operating Temperature		TOPR	-20 ~ +85	°C	
Junction Temperature		TJ	+125	°C	
Storage Temperature		TSTG	-40 ~ +150	°C	

Note:1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. The device could be damaged beyond Absolute maximum ratings.



LM386(A

## ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Operating Supply Voltage	Vss		4		12	V
Quiescent Current	lα	Vss=6V, VIN=0		4	8	mA
Output Dowor	5	Vss=6V, RL=8Ω, THD=10%	250	325		mW
	POUT	Vss=9V, RL=8Ω, THD=10%	500	700		
	0	Pin 1 and 8 Open		26		٩D
voltage Gain	Gv	10µF from pin 1 to pin 8		46		uв
D an da i dila	BW	Pin1 and pin 8 open	44	300		
Danuwiutn		10µF from pin 1 to pin 8	1	60		КПД
Total Harmonic	тип	Pout=125mW,Vs=6V,f=1kHz RL=8Ω	1	0.2		0/
Distortion	עחו	pin1 and pin 8 open		0.2		70
Rejection Ratio	D_	Vss=6V,f=1kHz,CBYPASS=10uF		50		dP
	ΓR	Pin1 and pin 8 open, Referred to output		50	2	uВ
Input Resistance	Rin		1.1	50		kΩ
Input Bias Current	IBIAS	Vss=6V Pin2 and pin 3 open	0	250		nA

#### APPLICATION NOTES GAIN CONTROL

To make the LM386 a more versatile amplifier, two pins(1and 8) are provided for gain control. With pins 1 and 8 open the 1.35 k $\Omega$  resistor sets the gain at 20(26dB),If a capacitor is put from pin 1 to 8,bypassing the 1.35 k $\Omega$  resistor, the gain will go up to 200(46dB).If a resistor is placed in series with the capacitor, the gain can be set to any value from 20 to 200.Gain control can also be done by capacitively coupling a resistor (or FET) from pin 1 to ground.

Additional external components can be placed in parallel with the internal feedback resistors to tailor the gain and frequency response for individual applications. For example we can compensate poor speaker bass response by frequency shaping the feedback path. This is done with a series RC from pin 1 to 5 (paralleling the internal 15 k $\Omega$  resistor). For 6 dB effective bass boost: R=15 k $\Omega$ , the lowest value for good stable operation is R=10 k $\Omega$ , if pin 8 is open, If pins 1 and 8 are bypassed then R as low as 2 k $\Omega$  can be used. This restriction is because the amplifier is only compensated for closed-loop gains greater than 9.

#### **INPUT BIASING**

The schematic shows that both inputs are biased to ground with a 50 k $\Omega$  resistor. The base current of the input transistors is about 250nA, so the inputs are at about 12.5mW when left open. If the dc source resistance driving the LM386 is higher than 250 k $\Omega$  it will contribute very little additional offset (about 2.5mW at the input, 50mW at the output). If the dc source resistance is less than 10 k $\Omega$ , then shorting the unused input to ground will keep the offset low (about 2.5mV at the input, 50 mV at the output). For dc source resistances between these values we can eliminate excess offset by putting a resistor from the unused input to ground, equal in value to the dc source resistance. Of course all offset problems are eliminated if the input is capacitively coupled.

When using the LM386 with higher gains (bypassing the 1.35 k $\Omega$  resistor between pins 1 and 8)it is necessary to bypass the unused input, preventing degradation of gain and possible instabilities. This is done with a 0.1µF capacitor or a short to ground depending on the dc source resistance on the driven input.



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# **TYPICAL APPLICATIONS CIRCUIT**









Low Distortion Power Wienbridge Oscillator 3900



Amplifier with Bass Boost





f=1kHz

≰1KΩ

Square Ware Oscillator





Note 1: Twist Supply lead and supply ground very tightly.

Note 2: Twist speaker lead and ground very tightly.

Note 3: Ferrite bead in Ferroxcube K5-001-001/3B with 3 turns of wire.

Note 4: R1C1 band limits input signals.

Note 5: All components must be spaced very closely to IC.



# LM386(A) LOW VOLTAGE AUDIO POWER AMPLIFIER

# **TYPICAL CHARACTERISTICS**



Peak-to -Peak Output Voltage Swing vs Supply Voltage



Voltage Gain vs Frequency



![](_page_4_Figure_8.jpeg)

Frequency Response With Bass Boost

![](_page_4_Figure_10.jpeg)

![](_page_4_Figure_11.jpeg)

Distortion vs Frequency

![](_page_4_Figure_13.jpeg)

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![](_page_5_Picture_0.jpeg)

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# **TYPICAL CHARACTERISTICS(cont.)**

![](_page_5_Figure_3.jpeg)

![](_page_5_Figure_4.jpeg)

Output Power (W)

Device Dissipaton vs Output Power -16QLoad

![](_page_5_Figure_7.jpeg)

![](_page_6_Picture_0.jpeg)

# Package information

SOP-8

![](_page_6_Figure_4.jpeg)

![](_page_6_Figure_5.jpeg)

![](_page_6_Figure_6.jpeg)

![](_page_6_Figure_7.jpeg)

Units		INCHES^	MILLIMETERS				
Dimension Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins n			8	1.		8	
Pitch	Р	$\sim$	0.050	) /		1.27	
Overall Height	А	0.053	0.061	0.069	1.35	1.55	1.75
Molded Package Thickness	A2	0.052	0.056	0.061	1.32	1.42	1.55
Standoff §		0.004	0.007	0.010	0.10	0.18	0.25
Overall Width E		0.228	0.237	0.244	5.79	6.02	6.20
Molded Package Width E <sup>2</sup>		0.146	0.154	0.157	3.71	3.91	3.99
Overall Length		0.189	0.193	0.197	4.80	4.90	5.00
Chamfer Distance	h	0.010	0.015	0.020	0.25	0.38	0.51
Foot Length	L	0.019	0.025	0.030	0.48	0.62	0.76
Foot Angle		0	4	8	0	4	8
Lead Thickness C		0.008	0.009	0.010	0.20	0.23	0.25
Lead Width B		0.013	0.017	0.020	0.33	0.42	0.51
Mold Draft Angle Top a		0	12	15	0	12	15
Mold Draft Angle Bottom		0	12	15	0	12	15

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![](_page_7_Picture_0.jpeg)

# LM386(A) LOW VOLTAGE AUDIO POWER AMPLIFIER

A2 -

## TSSOP-8

![](_page_7_Figure_3.jpeg)

![](_page_7_Figure_4.jpeg)

Units		INCHES <sup>^</sup>		22	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n			8		8		
Pitch	Р	10	0.026	3		0.65		
Overall Height	А		~	0.043			1.10	
Molded Package Thickness	A2	0.033	0.035	0.037	0.85	0.90	0.95	
Standoff §	A1	0.002	0.004	0.006	0.05	0.10	0.15	
Overall Width	E	0.246	0.251	0.256	6.25	6.38	6.50	
Molded Package Width	E1	0.169	0.173	0.177	4.30	4.40	4.50	
Molded Package Length	D	0.114	0.118	0.122	2.90	3.00	3.10	
Foot Length	L	0.020	0.024	0.028	0.50	0.60	0.70	
Foot Angle	Ø	0	4	8	0	4	8	
Lead Thickness	С	0.004	0.006	0.008	0.009	0.15	0.20	
Lead Width	В	0.007	0.010	0.012	0.19	0.25	0.30	
Mold Draft Angle Top	а	0	5	10	0	5	10	
Mold Draft Angle Bottom		0	5	10	0	5	10	

![](_page_8_Picture_0.jpeg)

# LM386(A) LOW VOLTAGE AUDIO POWER AMPLIFIER

DIP-8

![](_page_8_Figure_4.jpeg)

![](_page_8_Figure_5.jpeg)

![](_page_8_Figure_6.jpeg)

Units		INCHES <sup>^</sup>			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n	$\sim$	8	1.		8	
Pitch	Р	11	0.100	3		2.54	
Top to Seating Plane	Α	0.140	0.155	0.170	3.65	3.94	4.32
Molded Package Thickness	A2	0.115	0.130	0.145	2.92	3.30	3.68
Base to Seating Plane		0.015			0.38		
Shoulder to Shoulder Width		0.300	0.313	0.325	7.62	7.94	8.26
Molded Package Width		0.240	0.250	0.260	6.10	6.35	6.60
Overall Length		0.360	0.373	0.385	9.14	9.46	9.78
Tip to Seating Plane		0.125	0.130	0.135	3.18	3.30	3.43
Lead Thickness	С	0.008	0.012	0.015	0.20	0.29	0.38
Upper Lead Width	B1	0.045	0.058	0.070	1.14	1.46	1.78
Lower Lead Width		0.14	0.018	0.022	0.36	0.46	0.56
Overall Row Spacing §		0.310	0.370	0.430	7.87	9.40	10.92
Mold Draft Angle Top		5	10	15	5	10	15
Mold Draft Angle Bottom	ß	5	10	15	5	10	15